

Attorney Docket No. 200300117-1

Confirmation No. 9140

Group I, method for making a semiconductor device (claims 1 - 20); and

Group II, semiconductor devices (claims 21 - 24).

However, the two groups are not independent, as the fabrication method of Group I is specially adapted to make the nanoscopic semiconductor device structures of Group II. Furthermore, examination of these two groups together would not cause an undue burden of examination because the two groups have in common at least the first and second doped regions disclosed. Therefore, reconsideration and withdrawal of the restriction requirement are respectfully requested.

Examination of the application is also respectfully requested.

Respectfully submitted,

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